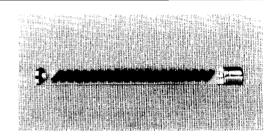


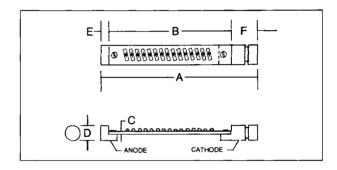
High Voltage Rectifier Assemblies For X-Ray Apparatus H701 H702 H703 H704

Micro Quality Semiconductor has designed this series of high voltage rectifier assemblies for use in X-Ray applications. The number of diodes mounted in series on a glass-epoxy printed circuit board is determined by the required peak reverse voltage. Each diode package contains a stack of controlled avalanche junctions.



LTR.	INCHES			MILLIMETERS				
	H701	H702	H703	H704	H701	H702	H703	H704
Α	5.60	6.70	9.06	9.06	142	170	230	230
В	4.61	5.71	8.07	8.07	117	145	205	205
С	.125	.125	.125	.125	3, 18	3, 18	3, 18	3, 18
D	.787	.787	.787	.787	20	20	20	20
E	.197	.197	.197	.197	5	5	5	5
F	.787	.787	.787	.787	20	20	20	20

Dimensional tolerances .XX ± .02", .XXX ± .005".



MAXIMUM RATINGS (At T_A = 25°C unless otherwise specified)

RATINGS	SYMBOL	H701	H702	H703	H704	UNITS
Peak Reverse Voltage—Operating (NOTE 1)	V _{R(oper)}	90	120	150	180	kV
Peak Reverse Voltage—Test	V _{R(test)}	100	135	170	200	kV
Peak Surge Current, 1/2 Cycle at 60 Hz (Non-Rep)	I _{FSM}			20		Amps
Peak Surge Current, 10 Cycles at 60 Hz	I _{FRM}	6			Amps	
DC Forward Current in 55°C oil (NOTE 1)	l _o	220			mA	
Junction Operating and Storage Temperature Range	T _J , T _{StG}	T _{.h} T _{sts} 55 to + 125				°C

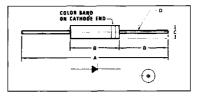
NOTE 1: To achieve rated current and voltage, diodes must be submerged in Shell Diala Oil AX electrical insulating oil or equivalent.

ELECTRICAL CHARACTERISTICS (At T_A = 25°C unless otherwise specified)

CHARACTERISTICS	SYMBOL	H701	H702	H703	H704	UNITS
Maximum Instantaneous Forward Voltage Drop at I _F = 50 mA	V _{FM}	120	168	204	240	Volts
Maximum Reverse Current at V _{R(Oper)}	1 _{RM}	.5	.5	.5	.5	μА
Maximum Reverse Current at V _{R(TEST)}	I _{RM}	1	1	1	1	μA
Number of Diodes Per Board		10	14	17	20	

Although purchase of the complete X-Ray board assembly is recommended, a high voltage, controlled avalanche diode (H463-3) may be purchased separately.

LTR.	INCHES	MILLIMETERS
Α	1.80	45,72
В	.60	15,24
Ç	.160 Dia.	4,06
D	.030034 Dia.	,76–,86
Dimens	sional tolerances .X	X±.02, .XXX± 005 Inch.



DIODE MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (At $T_A = 25^{\circ}$ C)

RATINGS & CHARACTERISTICS	SYMBOL	H463-3	UNITS
Peak Reserve Voltage—Operating	V _{B(oper)}	9	KV
Peak Reverse Voltage—Test	V _{R(test)}	10	KV
Peak Surge Current, 1/2 Cycle at 60Hz (Non-Rep) (Fig. 2)	I _{FSM}	20	Amps
Peak Surge Current, 10 Cycles at 60Hz	FRM	6	Amps
DC Forward Current in 55°C oil (Fig. 1)	10	220	mA
Junction Operating and Storage Temperature Range	T _J , T _{STG}	_ 55 to + 125	°C
Avalanche Energy, 100μ sec Pulse Width		.3	Joules
Maximum Instantaneous Forward Voltage Drop at I _F = 50mA	V _{FM}	12	Volts
Maximum Reverse Current at V _{R(test)}	I _{RM}	1	μА

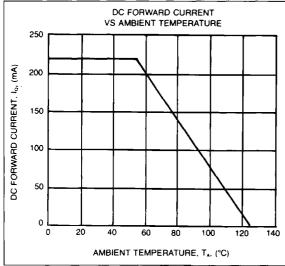


FIGURE 1

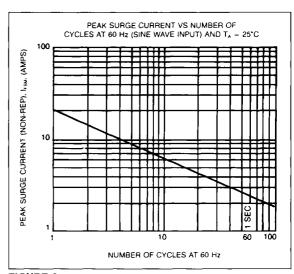


FIGURE 2